

## NCE N-Channel Enhancement Mode Power MOSFET

## **Description**

The NCE0117I uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

V<sub>DS</sub> =100V,I<sub>D</sub> =17A

 $R_{DS(ON)} < 48m\Omega @ V_{GS}=10V$  (Typ:42m $\Omega$ )

 $R_{DS(ON)} < 53m\Omega$  @  $V_{GS}=4.5V$  (Typ:44m $\Omega$ )

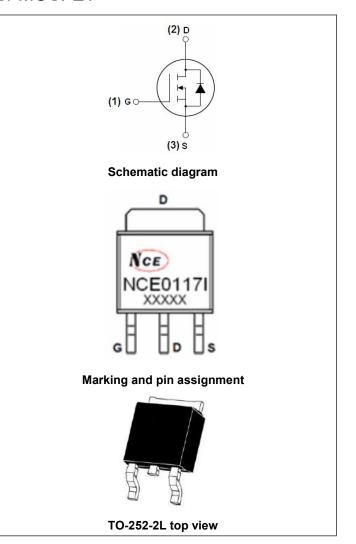
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

#### **Application**

- Power switching application
- Hard switched and high frequency circuits

100% UIS TESTED!

100% ΔVds TESTED!



### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0117I	NCE0117I	TO-251	-	-	-

## Absolute Maximum Ratings (T<sub>c</sub>=25℃unless otherwise noted)

<u> </u>			
Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	100	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	17	А
Drain Current-Continuous(T <sub>C</sub> =100°C)	I <sub>D</sub> (100℃)	12	А
Pulsed Drain Current	I <sub>DM</sub>	60	Α
Maximum Power Dissipation	P <sub>D</sub>	55	W
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	28	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	°C



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# **NCE0117I**

### **Thermal Characteristic**

Thermal Resistance,Junction-to-Case <sup>(Note 2)</sup>	Rejc	2.73	°C/W	l
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Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	100	110	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}=\pm20V, V_{DS}=0V$	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},I_{D}=250\mu A$	1.2	1.6	2.5	V
Dunin Course On Chata Benintana	Б	V <sub>GS</sub> =10V, I <sub>D</sub> =10A	-	42	48	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>			44	53	
Forward Transconductance	<b>G</b> FS	V <sub>DS</sub> =10V,I <sub>D</sub> =10A	-	14	-	S
Dynamic Characteristics (Note4)	-		'			
Input Capacitance	C <sub>lss</sub>	\/ 50\/\/ 0\/	-	1468	-	PF
Output Capacitance	Coss		-	62	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHZ	-	13.6	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	13.8	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =30 $V$ , $R_L$ =15 $\Omega$	-	9.3	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =2.5 $\Omega$	-	43.8	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	11.4	-	nS
Total Gate Charge	Qg	\/ F0\/   40A	-	40	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =50V,I <sub>D</sub> =10A,	-	4.4	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	9.5	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =17A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	17	Α
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is neg	ligible (tur	n-on is do	ominated b	y LS+LD

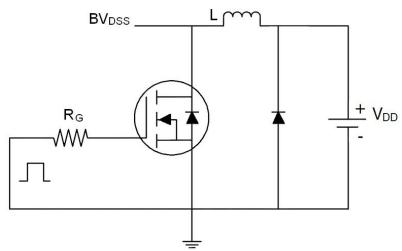
### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤  $300\mu$ s, Duty Cycle ≤ 2%.
- **4.** Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25  $^{\circ}\text{C}$  ,VDD=50V,VG=10V,L=0.5mH,Rg=25 $\Omega$

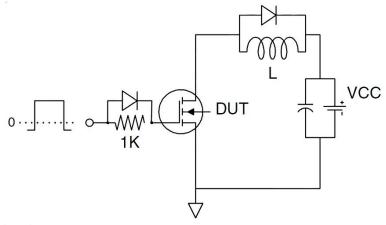


## **Test Circuit**

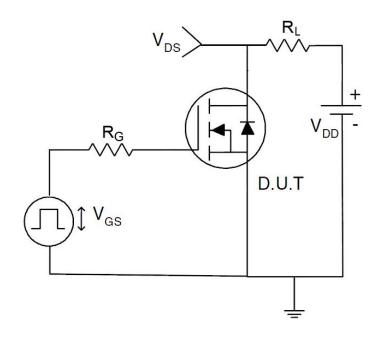
## 1) E<sub>AS</sub> test Circuit



## 2) Gate charge test Circuit

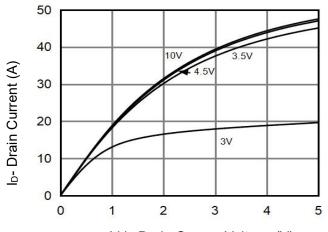


### 3) Switch Time Test Circuit





## Typical Electrical and Thermal Characteristics (Curves)



Vds Drain-Source Voltage (V)



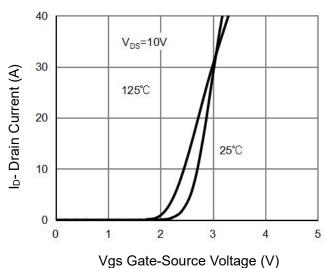
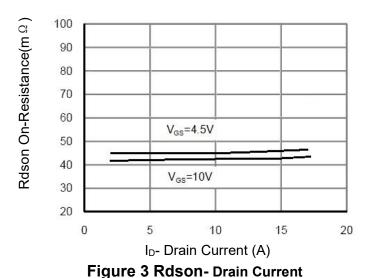


Figure 2 Transfer Characteristics



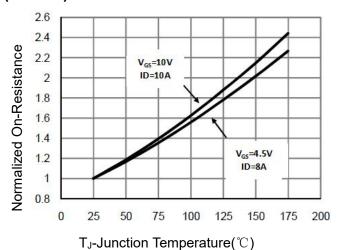


Figure 4 Rdson-JunctionTemperature

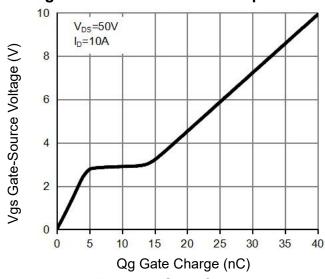


Figure 5 Gate Charge

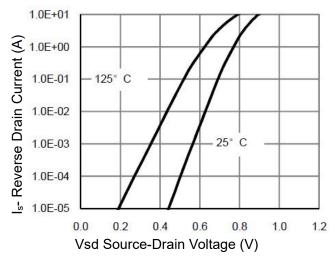


Figure 6 Source- Drain Diode Forward



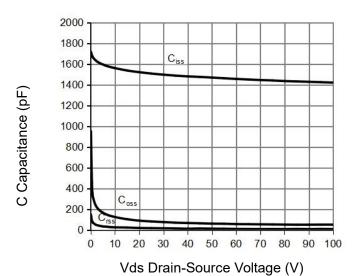


Figure 7 Capacitance vs Vds

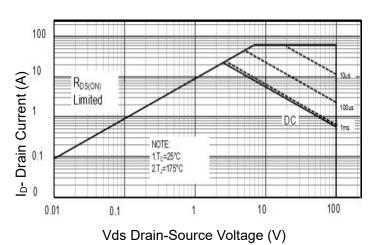


Figure 8 Safe Operation Area

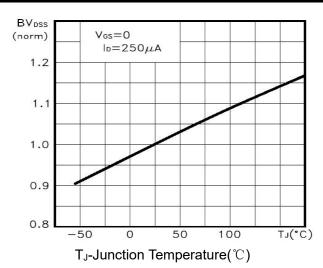


Figure 9 BV<sub>DSS</sub> vs Junction Temperature

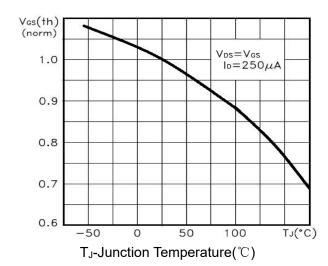
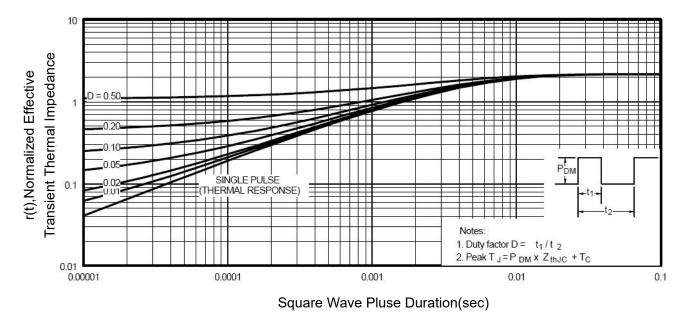


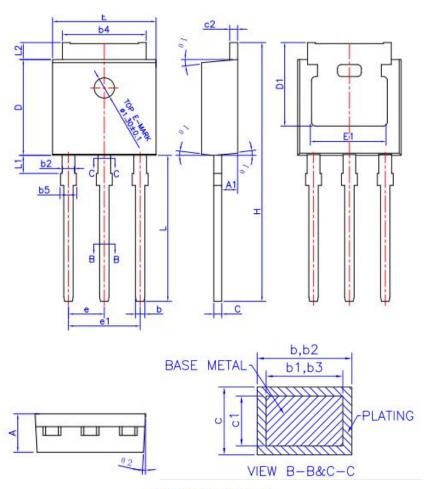
Figure 10 V<sub>GS(th)</sub> vs Junction Temperature



**Figure 11 Normalized Maximum Transient Thermal Impedance** 



## **TO-252-2L Package Information**



COMMON DIMENSIONS
(UNITS OF MEASURE =MILLIMETER)

SYMBOL	MIN	NOM	MAX
Α	2,20	2,30	2,35
A1	0.90	1.01	1.10
b	0.56		0.69
b1	0.55	0.60	0.65
b2	0.77		0.90
b3	0.76	0.81	0.86
b4	5.23	5.33	5.43
b5			1.05
С	0.46	(1) <del>(1) (</del> 1)	0.59
c1	0.45	0.51	0.55
c2	0.46		0.59
D	6.00	6.10	6.20
D1	5,20		
E	6.50	6.60	6.70
E1	4.60	4.83	5.00
e	2,24	2,29	2,34
e1	4.47	4.57	4,67
Н	16.18	16.48	16.78
L	9.00	9.30	9.60
L1	0.95	1,16	1,35
L2	0.90	1.08	1.25
01	3°	5°	7°
θ2	1°	3°	5°



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# NCE0117I

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